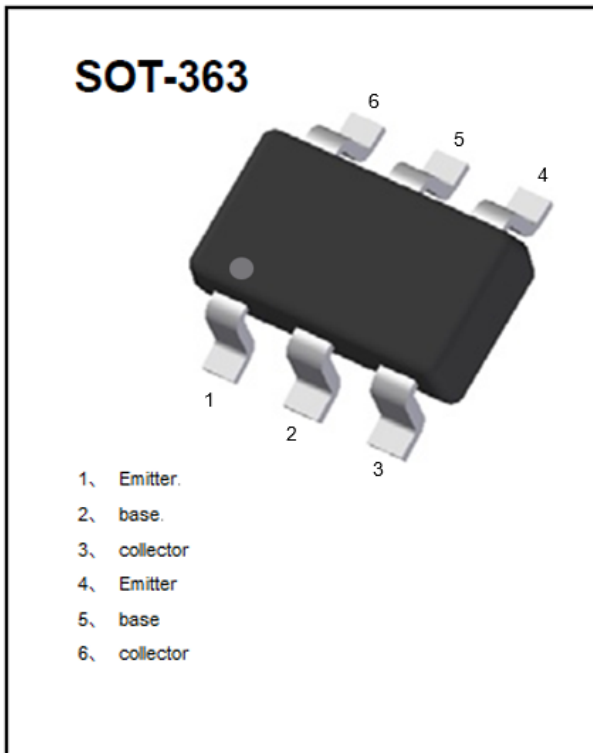


Dual PNP Small Signal Transistor



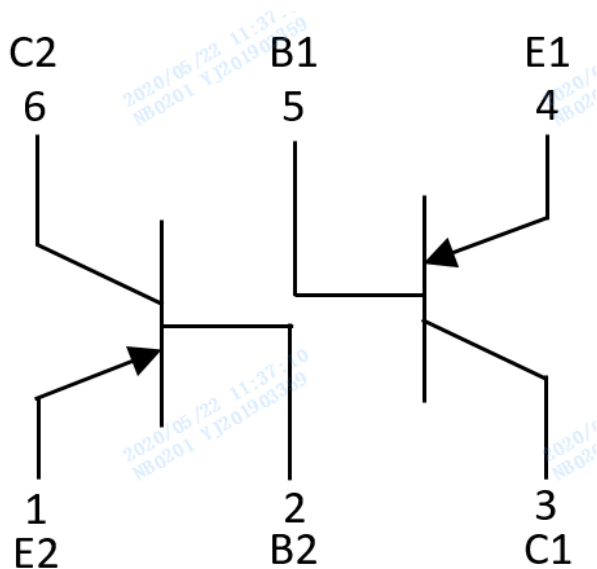
Features

- Epoxy meets UL-94 V-0 flammability rating
- Surface mount package ideally Suited for Automatic Insertion
- PNP

Mechanical Data

- **Package:** SOT-363
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Marking:** K4M

Equivalent circuit





MMDT5401

■Maximum Ratings (Ta=25°C Unless otherwise specified)

Item	Symbol	Unit	Conditions	Value
Collector-Base Voltage	VCBO	V	IC=-100μA, IE=0	-160
Collector-Emitter Voltage	VCEO	V	IC=-1mA, IB=0	-150
Emitter-Base Voltage	VEBO	V	IE=-10μA, IC=0	-5
Collector Current -Continuous	IC	mA		-600
Total Device Dissipation	PC	mW		200
Junction Temperature	Tj	°C		150
Storage Temperature	TSTG	°C		-55 to +150

■Electrical Characteristics (Ta=25°C unless otherwise specified)

Item	Symbol	Unit	Conditions	Min	TYP	Max
Collector-base breakdown voltage	V _{CBO}	V	IC=-100μA, IE=0	-160		
Collector-emitter breakdown voltage	V _{CEO}	V	IC=-1mA, IB=0	-150		
Emitter-base breakdown voltage	V _{EBO}	V	IE=-10μA, IC=0	-5		
Collector cut-off current	I _{CBO}	nA	VCB=-120V, IE=0			-50
Emmitter cut-off current	I _{EBO}	nA	VEB=-3V, IC=0			-50
DC current gain	h _{FE1}		VCE=-5V, IC=-1mA	50		
	h _{FE2}		VCE=-5V, IC=-10mA	100		300
	h _{FE3}		VCE=-5V, IC=-50mA	50		
Collector-emitter saturation voltage	V _{CE(sat)}	V	IC=-10mA, IB=-1mA			-0.2
Collector-emitter saturation voltage	V _{CE(sat)}	V	IC=-50mA, IB=-5mA			-0.5
Base-emitter saturation voltage	V _{BE(sat)}	V	IC=-10mA, IB=-1mA			-1
Base-emitter saturation voltage	V _{BE(sat)}	V	IC=-50mA, IB=-5mA			-1
Output Capacitance	Cob	pF	VCB=-10V, IE=0, f=1.0MHz			6
Transition frequency	f _T	MHz	VCE=-10V, IC=-10mA, f=100MHz	100		
Noise Figure	NF	dB	VCE=-5V, IC=-0.2mA, f=1kHz, RS=10Ω			8

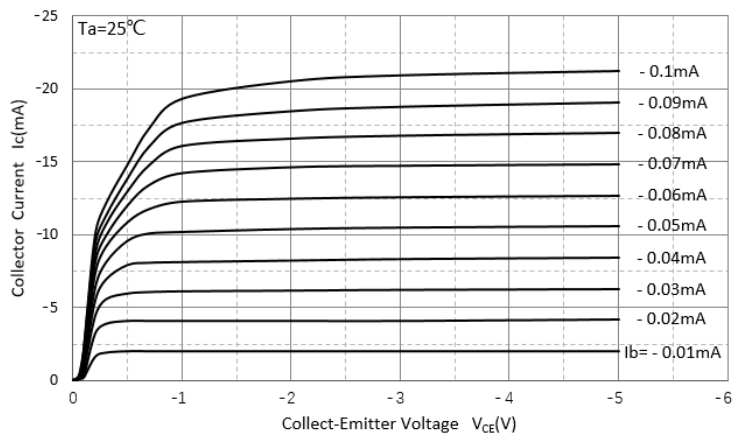
■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MMDT5401	F2	Approximate 0.009g	3000	30000	120000	7" reel

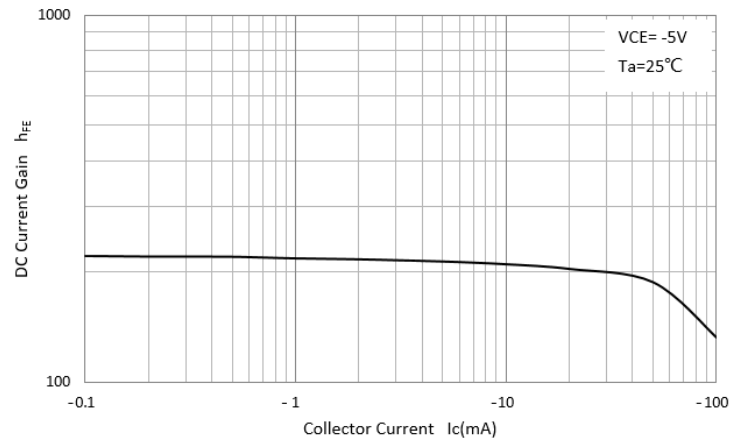


■ Characteristics (Typical)

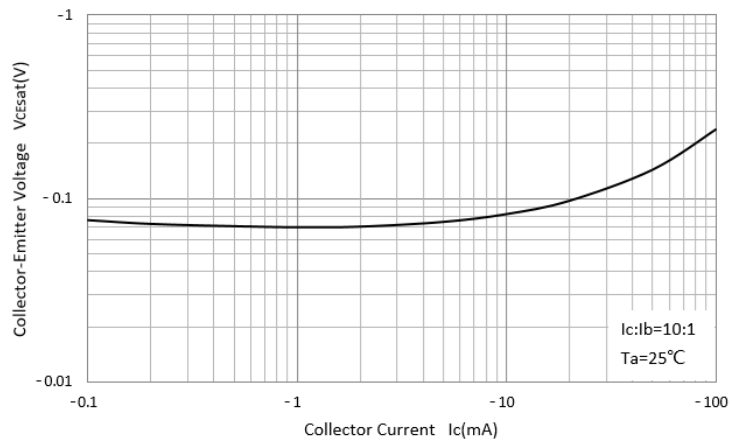
Static Characteristic



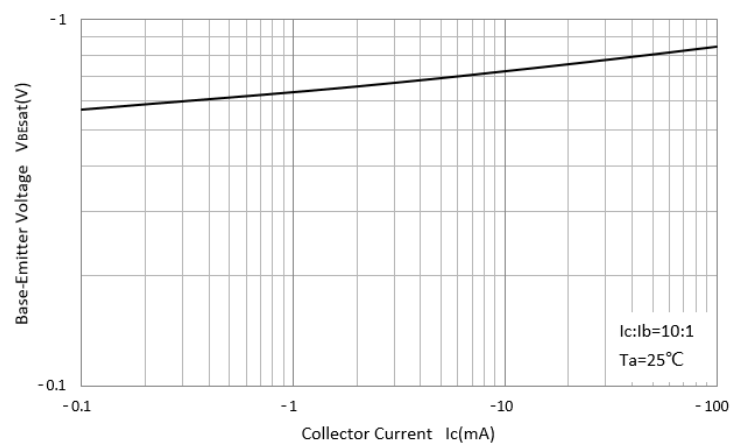
DC Current Gain



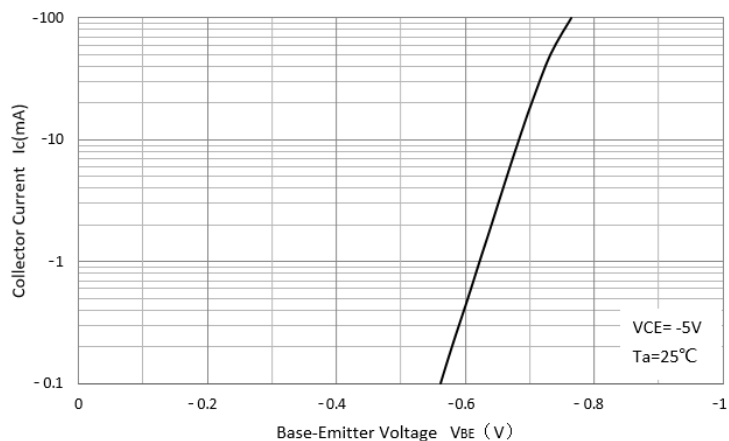
Collector-Emittor Saturation Voltage



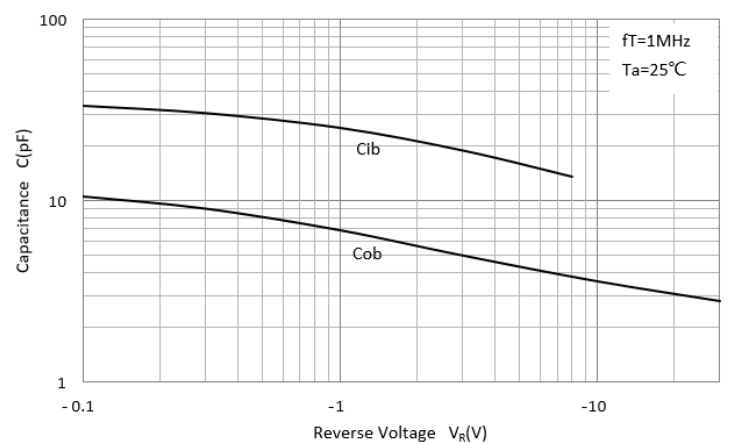
Base-Emittor Saturation Voltage



Base-Emittor On Voltage



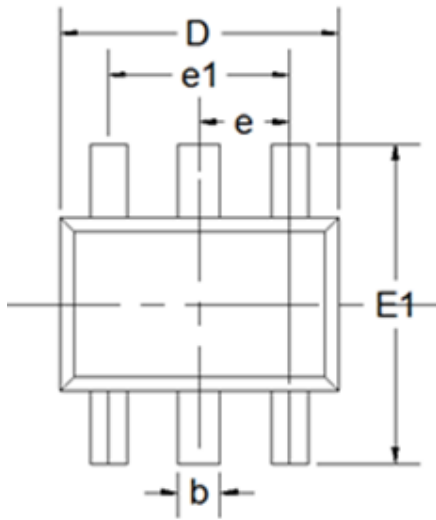
$C_{ob}/C_{ib}-V_{CB}/V_{EB}$



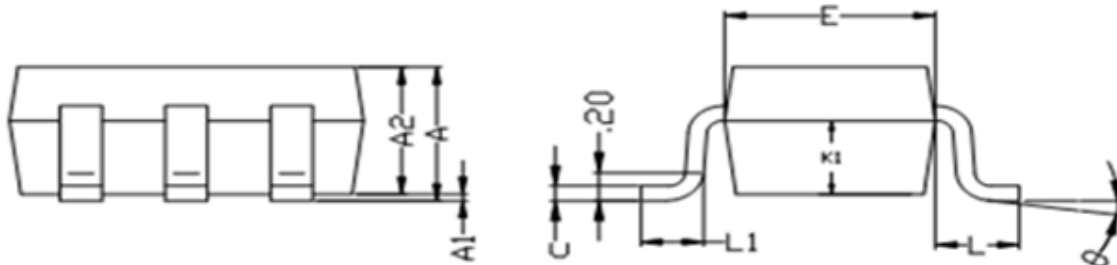


MMDT5401

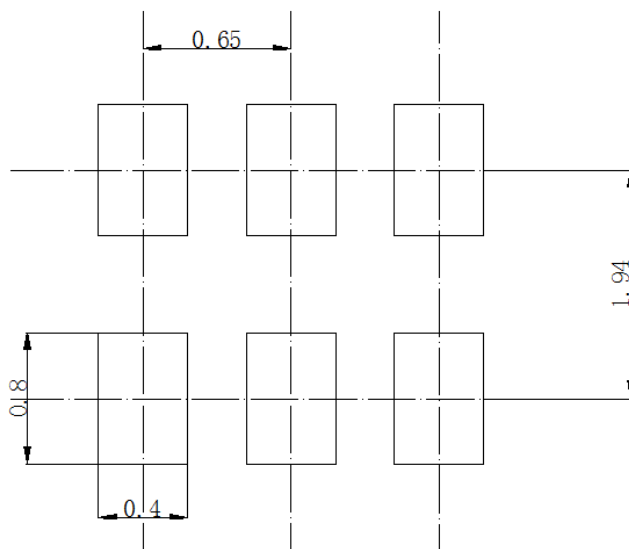
■SOT-363 Package Outline Dimensions



DIM	DIMENSIONS			
	INCHES		MM	
	MIN	MAX	MIN	MAX
A	0.035	0.043	0.9	1.1
A1	0	0.004	0	0.1
A2	0.035	0.039	0.9	1
b	0.006	0.014	0.15	0.35
c	0.002	0.01	0.05	0.25
D	0.071	0.087	1.8	2.2
E	0.045	0.053	1.15	1.35
E1	0.085	0.096	2.15	2.45
e	0.026Typ		0.65Typ	
e1	0.047	0.055	1.2	1.4
L	0.021Typ		0.525Typ	
L1	0.01	0.018	0.26	0.46
θ	0°		8°	



■SOT-363 Soldering Footprint



Unit: mm



Disclaimer

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